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Facile preparation and performance of novel high-T_C xBi(Ni_{1/2}Ti_{1/2})O₃-(1-x)Pb(Zr_{1/2}Ti_{1/2})O₃ piezoceramics

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Abstract: High Curie temperature (T_C) xBi $(Ni_{1/2}Ti_{1/2})O_3$ - $(1-x)Pb(Zr_{1/2}Ti_{1/2})O_3$

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